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PIC16(L)F1826/27 Data Sheet

18/20/28-Pin Flash Microcontrollers with nanoWatt XLP Technology

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18/20/28-Pin Flash Microcontrollers with nanoWatt XLP Technology

High-Performance RISC CPU:

- · C Compiler Optimized Architecture
- · 256 bytes Data EEPROM
- Up to 8 Kbytes Linear Program Memory Addressing
- · Up to 384 bytes Linear Data Memory Addressing
- · Interrupt Capability with Automatic Context Saving
- 16-Level Deep Hardware Stack with Optional Overflow/Underflow Reset
- · Direct, Indirect and Relative Addressing modes:
 - Two full 16-bit File Select Registers (FSRs)
 - FSRs can read program and data memory

Flexible Oscillator Structure:

- Precision 32 MHz Internal Oscillator Block:
 - Factory calibrated to ± 1%, typical
 - Software selectable frequencies range of 31 kHz to 32 MHz
- · 31 kHz Low-Power Internal Oscillator
- · Four Crystal modes up to 32 MHz
- Three External Clock modes up to 32 MHz
- 4X Phase-Lock Loop (PLL)
- Fail-Safe Clock Monitor:
 - Allows for safe shutdown if peripheral clock stops
- · Two-Speed Oscillator Start-up
- Reference Clock Module:
 - Programmable clock output frequency and duty-cycle

Special Microcontroller Features:

- 1.8V-5.5V Operation PIC16F1826/27
- 1.8V-3.6V Operation PIC16LF1826/27
- · Self-Programmable under Software Control
- Power-on Reset (POR), Power-up Timer (PWRT) and Oscillator Start-up Timer (OST)
- Programmable Brown-out Reset (BOR)
- Extended Watchdog Timer (WDT):
 - Programmable period from 1ms to 268s
- · Programmable Code Protection
- In-Circuit Serial Programming™ (ICSP™) via two pins
- In-Circuit Debug (ICD) via two pins
- · Enhance Low-Voltage Programming
- · Power-Saving Sleep mode

Extreme Low-Power Management PIC16LF1826/27 with nanoWatt XLP:

- Operating Current: 75 μA @ 1 MHz, 1.8V, typical
- Sleep mode: 30 nAWatchdog Timer: 500 nA
- Timer1 Oscillator: 600 nA @ 32 kHz

Analog Features:

- · Analog-to-Digital Converter (ADC) Module:
 - 10-bit resolution, 12 channels
 - Auto acquisition capability
 - Conversion available during Sleep
- Analog Comparator Module:
 - Two rail-to-rail analog comparators
 - Power mode control
 - Software controllable hysteresis
- · Voltage Reference Module:
 - Fixed Voltage Reference (FVR) with 1.024V, 2.048V and 4.096V output levels
 - 5-bit rail-to-rail resistive DAC with positive and negative reference selection

Peripheral Highlights:

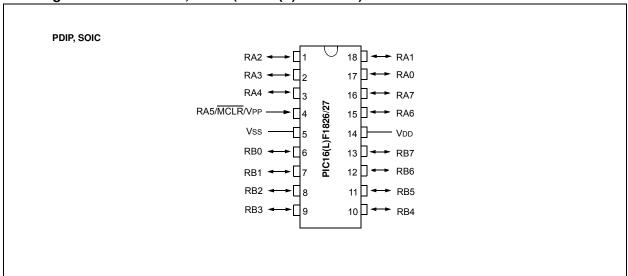
- 15 I/O Pins and 1 Input Only Pin:
 - High current sink/source 25 mA/25 mA
 - Programmable weak pull-ups
 - Programmable interrupt-on- change pins
- Timer0: 8-Bit Timer/Counter with 8-Bit Prescaler
- · Enhanced Timer1:
 - 16-bit timer/counter with prescaler
 - External Gate Input mode
 - Dedicated, low-power 32 kHz oscillator driver
- Up to three Timer2-types: 8-Bit Timer/Counter with 8-Bit Period Register, Prescaler and Postscaler
- Up to two Capture, Compare, PWM (CCP) Modules
- Up to two Enhanced CCP (ECCP) Modules:
 - Software selectable time bases
 - Auto-shutdown and auto-restart
 - PWM steering
- Up to two Master Synchronous Serial Port (MSSP) with SPI and I²C[™] with:
 - 7-bit address masking
 - SMBus/PMBus™ compatibility
- Enhanced Universal Synchronous Asynchronous Receiver Transmitter (EUSART) Module
- mTouch™ Sensing Oscillator Module:
 - Up to 12 input channels
- · Data Signal Modulator Module:
 - Selectable modulator and carrier sources
- · SR Latch:
 - Multiple Set/Reset input options
 - Emulates 555 Timer applications

PIC16(L)F1826/27 Family Types

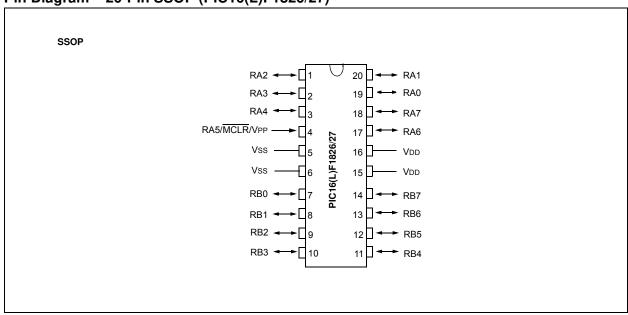
	Program Memory		ata nory		(ch)	(ch)	rs	-bit)			idge)	idge)		
Device	Words	SRAM (bytes)	Data EEPROM (bytes)	I/O's ⁽¹⁾	10-bit ADC (CapSense (Comparato	Timers (8/16-	EUSART	dssw	ECCP (Full-Bridge)	ECCP (Half-Bridge)	CCP	SR Latch
PIC16LF1826	2K	256	256	16	12	12	2	2/1	1	1	1	_	_	Yes
PIC16F1826	2K	256	256	16	12	12	2	2/1	1	1	1	_	_	Yes
PIC16LF1827	4K	384	256	16	12	12	2	4/1	1	2	1	1	2	Yes
PIC16F1827	4K	384	256	16	12	12	2	4/1	1	2	1	1	2	Yes

Note 1: One pin is input only.

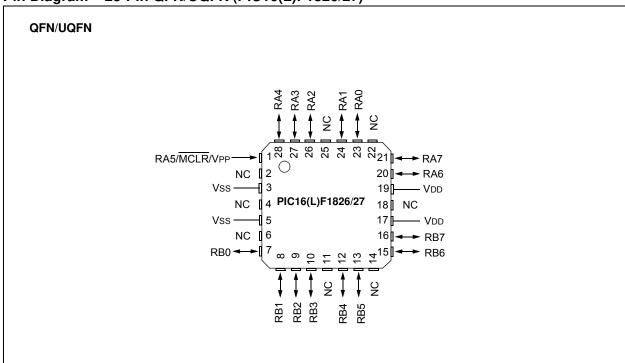
Pin Diagram - 18-Pin PDIP, SOIC (PIC16(L)F1826/27)



Pin Diagram - 20-Pin SSOP (PIC16(L)F1826/27)



Pin Diagram – 28-Pin QFN/UQFN (PIC16(L)F1826/27)



18/20/28-PIN SUMMARY (PIC16(L)F1826/27) TABLE 1:

I/O	18-Pin PDIP/SOIC	20-Pin SSOP	28-Pin QFN/UQFN	ANSEL	A/D	Reference	Cap Sense	Comparator	SR Latch	Timers	ССР	EUSART	MSSP	Interrupt	Modulator	Pull-up	Basic
RA0	17	19	23	Υ	AN0	_	CPS0	C12IN0-	_	_	_	_	SDO2 ⁽²⁾		_	N	_
RA1	18	20	24	Υ	AN1	_	CPS1	C12IN1-	_	_	_	_	SS2 ⁽²⁾	_	_	Ν	_
RA2	1	1	26	Υ	AN2	VREF- DACOUT	CPS2	C12IN2- C12IN+	1	1	_	_	-	1	_	Ν	_
RA3	2	2	27	Υ	AN3	VREF+	CPS3	C12IN3- C1IN+ C1OUT	SRQ		CCP3 ⁽²⁾	_		_	_	N	_
RA4	3	3	28	Υ	AN4	_	CPS4	C2OUT	SRNQ	T0CKI	CCP4 ⁽²⁾	_		_	_	N	_
RA5	4	4	1	N	_	_		_	_	_		_	SS1 ⁽¹⁾		_	Y ⁽³⁾	MCLR, VPP
RA6	15	17	20	N	_		_	_	1	1	P1D ⁽¹⁾ P2B ^(1,2)	I	SDO1 ⁽¹⁾	-	_	N	OSC2 CLKOUT CLKR
RA7	16	18	21	N	_	_	_	_	1	1	P1C ⁽¹⁾ CCP2 ^(1,2) P2A ^(1,2)		-	_	_	N	OSC1 CLKIN
RB0	6	7	7	N	ı	_	1		SRI	T1G	CCP1 ⁽¹⁾ P1A ⁽¹⁾ FLT0			INT IOC	_	Υ	_
RB1	7	8	8	Υ	AN11	_	CPS11	_		-	_	RX ^(1,4) DT ^(1,4)	SDA1 SDI1	IOC	_	Υ	_
RB2	8	9	9	Y	AN10	_	CPS10	_	_	_	_	RX ⁽¹⁾ ,DT ⁽¹⁾ TX ^(1,4) CK ^(1,4)	SDA2 ⁽²⁾ SDI2 ⁽²⁾ SDO1 ^(1,4)	IOC	MDMIN	Υ	_
RB3	9	10	10	Υ	AN9	_	CPS9	_		-	CCP1 ^(1,4) P1A ^(1,4)	_	_	IOC	MDOUT	Υ	_
RB4	10	11	12	Υ	AN8	_	CPS8	_	_	_	_	_	SCL1 SCK1	IOC	MDCIN2	Υ	_
RB5	11	12	13	Y	AN7	_	CPS7		1	1	P1B	TX ⁽¹⁾ CK ⁽¹⁾	SCL2 ⁽²⁾ SCK2 ⁽²⁾ SS1 ^(1,4)	IOC	_	Y	_
RB6	12	13	15	Y	AN5	_	CPS5	_	1	T1CKI T1OSI	P1C ^(1,4) CCP2 ^(1,2,4) P2A ^(1,2,4)	_	_	IOC	_	Y	ICSPCLK/ ICDCLK
RB7	13	14	16	Υ	AN6	_	CPS6	1		T10S0	P1D ^(1,4) P2B ^(1,2,4)	_	_	IOC	MDCIN1	Υ	ICSPDAT/ ICDDAT
VDD	14	15,16	17,19	_	_	_	_	_	_	_	_	_	_	_	_	_	Vdd
Vss	5	5,6	3,5	_	_	_	-	_	_	_	-	_	_	-	_	_	Vss

Note 1: Pin functions can be moved using the APFCON0 or APFCON1 register.
2: Functions are only available on the PIC16(L)F1827.
3: Weak pull-up always enabled when MCLR is enabled, otherwise the pull-up is under user control.
4: Default function location.

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1.0 DEVICE OVERVIEW

The PIC16(L)F1826/27 are described within this data sheet. They are available in 18/20/28-pin packages. Figure 1-1 shows a block diagram of the PIC16(L)F1826/27 devices. Table 1-2 shows the pinout descriptions.

Reference Table 1-1 for peripherals available per device.

TABLE 1-1: DEVICE PERIPHERAL SUMMARY

Peripheral		PIC16F/LF1826	PIC16(L)F1827
ADC		•	•
Capacitive Sensing Mod	dule	•	•
Digital-to-Analog Conve	erter (DAC)	•	•
Digital Signal Modulator	r (DSM)	•	•
EUSART		•	•
Fixed Voltage Reference	e (FVR)	•	•
Reference Clock Modul	е	•	•
SR Latch	•	•	
Capture/Compare/PWM	1 Modules		
	ECCP1	•	•
	ECCP2		•
	CCP3		•
	CCP4		•
Comparators			
	C1	•	•
	C2	•	•
Master Synchronous Se	erial Ports		
	MSSP1	•	•
	MSSP2		•
Timers			
	Timer0	•	•
	Timer1	•	•
	Timer2	•	•
	Timer4		•
	Timer6		•

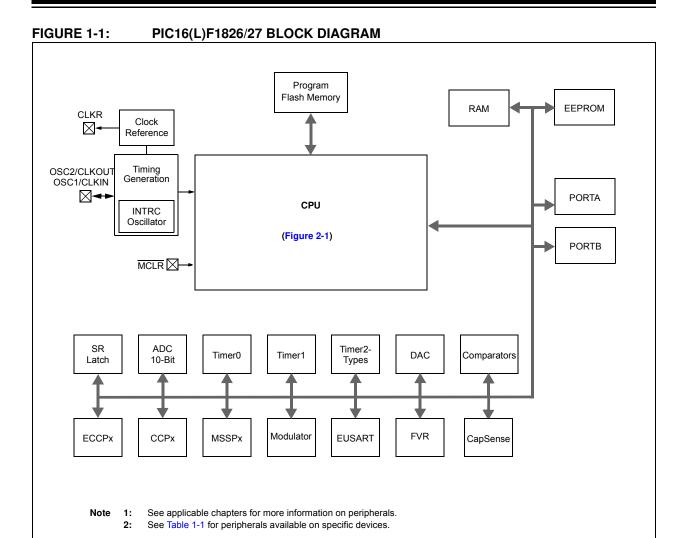


TABLE 1-2: PIC16(L)F1826/27 PINOUT DESCRIPTION

Name	Function	Input Type	Output Type	Description
RA0/AN0/CPS0/C12IN0-/	RA0	TTL	CMOS	General purpose I/O.
SDO2 ⁽²⁾	AN0	AN	_	A/D Channel 0 input.
	CPS0	AN	_	Capacitive sensing input 0.
	C12IN0-	AN	_	Comparator C1 or C2 negative input.
	SDO2		CMOS	SPI data output.
RA1/AN1/CPS1/C12IN1-/SS2 ⁽²⁾	RA1	TTL	CMOS	General purpose I/O.
	AN1	AN	_	A/D Channel 1 input.
	CPS1	AN	_	Capacitive sensing input 1.
	C12IN1-	AN	_	Comparator C1 or C2 negative input.
	SS2	ST	_	Slave Select input 2.
RA2/AN2/CPS2/C12IN2-/	RA2	TTL	CMOS	General purpose I/O.
C12IN+/VREF-/DACOUT	AN2	AN	_	A/D Channel 2 input.
	CPS2	AN	_	Capacitive sensing input 2.
	C12IN2-	AN	_	Comparator C1 or C2 negative input.
	C12IN+	AN	_	Comparator C1 or C2 positive input.
	VREF-	AN	_	A/D Negative Voltage Reference input.
	DACOUT	_	AN	Voltage Reference output.
RA3/AN3/CPS3/C12IN3-/C1IN+/	RA3	TTL	CMOS	General purpose I/O.
VREF+/C1OUT/CCP3 ⁽²⁾ /SRQ	AN3	AN	_	A/D Channel 3 input.
	CPS3	AN	_	Capacitive sensing input 3.
	C12IN3-	AN	_	Comparator C1 or C2 negative input.
	C1IN+	AN	_	Comparator C1 positive input.
	VREF+	AN	_	A/D Voltage Reference input.
	C1OUT	_	CMOS	Comparator C1 output.
	CCP3	ST	CMOS	Capture/Compare/PWM3.
	SRQ		CMOS	SR latch non-inverting output.
RA4/AN4/CPS4/C2OUT/T0CKI/	RA4	TTL	CMOS	General purpose I/O.
CCP4 ⁽²⁾ /SRNQ	AN4	AN	_	A/D Channel 4 input.
	CPS4	AN	_	Capacitive sensing input 4.
	C2OUT	_	CMOS	Comparator C2 output.
	T0CKI	ST	_	Timer0 clock input.
	CCP4	ST	CMOS	Capture/Compare/PWM4.
	SRNQ	_	CMOS	SR latch inverting output.
RA5/MCLR/VPP/SS1(1,2)	RA5	TTL	CMOS	General purpose I/O.
	MCLR	ST	_	Master Clear with internal pull-up.
	VPP	HV	_	Programming voltage.
	SS1	ST	_	Slave Select input 1.

Legend: AN = Analog input or output CMOS = CMOS compatible input or output OD = Open Drain

TTL = TTL compatible input ST = Schmitt Trigger input with CMOS levels 1^2C^{TM} = Schmitt Trigger input with 1^2C HV = High Voltage XTAL = Crystal levels

Note 1: Pin functions can be moved using the APFCON0 or APFCON1 register.

2: Functions are only available on the PIC16(L)F1827.

TABLE 1-2: PIC16(L)F1826/27 PINOUT DESCRIPTION (CONTINUED)

Name	Function	Input Type	Output Type	Description
RA6/OSC2/CLKOUT/CLKR/	RA6	TTL	CMOS	General purpose I/O.
P1D ⁽¹⁾ /P2B ^(1,2) /SDO1 ⁽¹⁾	OSC2	_	XTAL	Crystal/Resonator (LP, XT, HS modes).
	CLKOUT	_	CMOS	Fosc/4 output.
	CLKR	_	CMOS	Clock Reference Output.
	P1D	_	CMOS	PWM output.
	P2B	_	CMOS	PWM output.
	SDO1	_	CMOS	SPI data output 1.
RA7/OSC1/CLKIN/P1C ⁽¹⁾ /	RA7	TTL	CMOS	General purpose I/O.
CCP2 ^(1,2) /P2A ^(1,2)	OSC1	XTAL	_	Crystal/Resonator (LP, XT, HS modes).
	CLKIN	CMOS	_	External clock input (EC mode).
	P1C	_	CMOS	PWM output.
	CCP2	ST	CMOS	Capture/Compare/PWM2.
	P2A	_	CMOS	PWM output.
RB0/T1G/CCP1 ⁽¹⁾ /P1A ⁽¹⁾ /INT/ SRI/FLT0	RB0	TTL	CMOS	General purpose I/O. Individually controlled interrupt-on-change. Individually enabled pull-up.
	T1G	ST	_	Timer1 Gate input.
	CCP1	ST	CMOS	Capture/Compare/PWM1.
	P1A	_	CMOS	PWM output.
	INT	ST	_	External interrupt.
	SRI	ST	_	SR latch input.
	FLT0	ST	_	ECCP Auto-Shutdown Fault input.
RB1/AN11/CPS11/RX ^(1,3) / DT ^(1,3) /SDA1/SDI1	RB1	TTL	CMOS	General purpose I/O. Individually controlled interrupt-on-change. Individually enabled pull-up.
	AN11	AN	_	A/D Channel 11 input.
	CPS11	AN	_	Capacitive sensing input 11.
	RX	ST	_	USART asynchronous input.
	DT	ST	CMOS	USART synchronous data.
	SDA1	I ² C™	OD	I ² C™ data input/output 1.
	SDI1	CMOS	_	SPI data input 1.
RB2/AN10/CPS10/MDMIN/ TX ^(1,3) /CK ^(1,3) /RX ⁽¹⁾ /DT ⁽¹⁾ /	RB2	TTL	CMOS	General purpose I/O. Individually controlled interrupt-on-change. Individually enabled pull-up.
SDA2 ⁽²⁾ /SDI2 ⁽²⁾ /SDO1 ^(1,3)	AN10	AN	_	A/D Channel 10 input.
	CPS10	AN	_	Capacitive sensing input 10.
	MDMIN	_	CMOS	Modulator source input.
	TX	_	CMOS	USART asynchronous transmit.
	CK	ST	CMOS	USART synchronous clock.
	RX	ST	_	USART asynchronous input.
	DT	ST	CMOS	USART synchronous data.
	SDA2	I ² C™	OD	I ² C™ data input/output 2.
	SDI2	ST	_	SPI data input 2.
	SDO1	_	CMOS	SPI data output 1.

Legend: AN = Analog input or output CMOS = CMOS compatible input or output OD = Open Drain

TTL = TTL compatible input ST = Schmitt Trigger input with CMOS levels I^2C^{TM} = Schmitt Trigger input with I^2C HV = High Voltage ST = Schmitt Trigger input with S

Note 1: Pin functions can be moved using the APFCON0 or APFCON1 register.

2: Functions are only available on the PIC16(L)F1827.

TABLE 1-2: PIC16(L)F1826/27 PINOUT DESCRIPTION (CONTINUED)

Name	Function	Input Type	Output Type	Description
RB3/AN9/CPS9/MDOUT/ CCP1 ^(1,3) /P1A ^(1,3)	RB3	TTL	CMOS	General purpose I/O. Individually controlled interrupt-on-change. Individually enabled pull-up.
	AN9	AN	_	A/D Channel 9 input.
	CPS9	AN	_	Capacitive sensing input 9.
	MDOUT	_	CMOS	Modulator output.
	CCP1	ST	CMOS	Capture/Compare/PWM1.
	P1A		CMOS	PWM output.
RB4/AN8/CPS8/SCL1/SCK1/ MDCIN2	RB4	TTL	CMOS	General purpose I/O. Individually controlled interrupt-on-change. Individually enabled pull-up.
	AN8	AN	_	A/D Channel 8 input.
	CPS8	AN	_	Capacitive sensing input 8.
	SCL1	I ² C™	OD	I ² C™ clock 1.
	SCK1	ST	CMOS	SPI clock 1.
	MDCIN2	ST	_	Modulator Carrier Input 2.
RB5/AN7/CPS7/P1B/TX ⁽¹⁾ /CK ⁽¹⁾ /SCL2 ⁽²⁾ /SCK2 ⁽²⁾ /SS1 ^(1,3)	RB5	TTL	CMOS	General purpose I/O. Individually controlled interrupt-on-change. Individually enabled pull-up.
	AN7	AN	_	A/D Channel 7 input.
	CPS7	AN	_	Capacitive sensing input 7.
	P1B	_	CMOS	PWM output.
	TX	_	CMOS	USART asynchronous transmit.
	CK	ST	CMOS	USART synchronous clock.
	SCL2	I ² C™	OD	I ² C™ clock 2.
	SCK2	ST	CMOS	SPI clock 2.
	SS1	ST	_	Slave Select input 1.
RB6/AN5/CPS5/T1CKI/T1OSI/ P1C ^(1,3) /CCP2 ^(1,2,3) /P2A ^(1,2,3) /	RB6	TTL	CMOS	General purpose I/O. Individually controlled interrupt-on-change. Individually enabled pull-up.
ICSPCLK	AN5	AN	_	A/D Channel 5 input.
	CPS5	AN	_	Capacitive sensing input 5.
	T1CKI	ST	_	Timer1 clock input.
	T10S0	XTAL	XTAL	Timer1 oscillator connection.
	P1C	1	CMOS	PWM output.
	CCP2	ST	CMOS	Capture/Compare/PWM2.
	P2A	-	CMOS	PWM output.
	ICSPCLK	ST	_	Serial Programming Clock.
RB7/AN6/CPS6/T1OSO/ P1D ^(1,3) /P2B ^(1,2,3) /MDCIN1/	RB7	TTL	CMOS	General purpose I/O. Individually controlled interrupt-on-change. Individually enabled pull-up.
ICSPDAT	AN6	AN	_	A/D Channel 6 input.
	CPS6	AN	_	Capacitive sensing input 6.
	T1OSO	XTAL	XTAL	Timer1 oscillator connection.
	P1D	_	CMOS	PWM output.
	P2B	-	CMOS	PWM output.
	MDCIN1	ST		Modulator Carrier Input 1.
	ICSPDAT	ST	CMOS	ICSP™ Data I/O.

Legend: AN = Analog input or output CMOS = CMOS compatible input or output OD = Open Drain

TTL = TTL compatible input ST = Schmitt Trigger input with CMOS levels I^2C^{TM} = Schmitt Trigger input with I^2C HV = High Voltage XTAL = Crystal levels

Note 1: Pin functions can be moved using the APFCON0 or APFCON1 register.

2: Functions are only available on the PIC16(L)F1827.

TABLE 1-2: PIC16(L)F1826/27 PINOUT DESCRIPTION (CONTINUED)

Name	Function	Input Type	Output Type	Description
VDD	VDD	Power	_	Positive supply.
Vss	Vss	Power	_	Ground reference.

Legend: AN = Analog input or output CMOS = CMOS compatible input or output OD = Open Drain

TTL = TTL compatible input ST = Schmitt Trigger input with CMOS levels 1^2C^{TM} = Schmitt Trigger input with 1^2C

HV = High Voltage XTAL = Crystal levels

Note 1: Pin functions can be moved using the APFCON0 or APFCON1 register.

2: Functions are only available on the PIC16(L)F1827.

2.0 ENHANCED MID-RANGE CPU

This family of devices contain an enhanced mid-range 8-bit CPU core. The CPU has 49 instructions. Interrupt capability includes automatic context saving. The hardware stack is 16 levels deep and has Overflow and Underflow Reset capability. Direct, Indirect, and Relative addressing modes are available. Two File Select Registers (FSRs) provide the ability to read program and data memory.

- · Automatic Interrupt Context Saving
- · 16-level Stack with Overflow and Underflow
- · File Select Registers
- · Instruction Set

2.1 Automatic Interrupt Context Saving

During interrupts, certain registers are automatically saved in shadow registers and restored when returning from the interrupt. This saves stack space and user code. See Section 8.5 "Automatic Context Saving", for more information.

2.2 16-level Stack with Overflow and Underflow

These devices have an external stack memory 15 bits wide and 16 words deep. A Stack Overflow or Underflow will set the appropriate bit (STKOVF or STKUNF) in the PCON register, and if enabled will cause a software Reset. See section **Section 3.4 "Stack"** for more details.

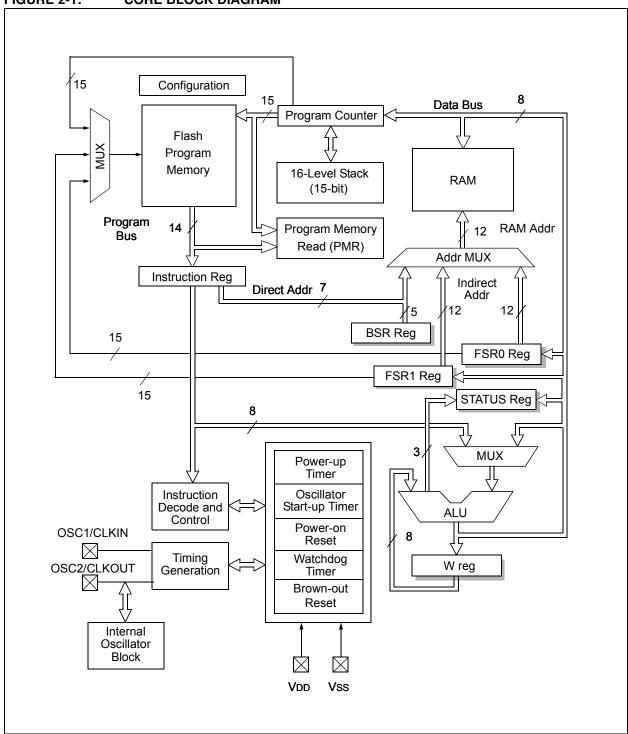
2.3 File Select Registers

There are two 16-bit File Select Registers (FSR). FSRs can access all file registers and program memory, which allows one Data Pointer for all memory. When an FSR points to program memory, there is one additional instruction cycle in instructions using INDF to allow the data to be fetched. General purpose memory can now also be addressed linearly, providing the ability to access contiguous data larger than 80 bytes. There are also new instructions to support the FSRs. See Section 3.4 "Stack"for more details.

2.4 Instruction Set

There are 49 instructions for the enhanced mid-range CPU to support the features of the CPU. See Section 29.0 "Instruction Set Summary" for more details.

FIGURE 2-1: CORE BLOCK DIAGRAM



3.0 MEMORY ORGANIZATION

There are three types of memory in PIC16(L)F1826/27: Data Memory, Program Memory and Data EEPROM Memory⁽¹⁾.

- · Program Memory
- · Data Memory
 - Core Registers
 - Special Function Registers
 - General Purpose RAM
 - Common RAM
 - Device Memory Maps
 - Special Function Registers Summary
- Data EEPROM memory⁽¹⁾

Note 1: The Data EEPROM Memory and the method to access Flash memory through the EECON registers is described in Section 11.0 "Data EEPROM and Flash Program Memory Control".

The following features are associated with access and control of program memory and data memory:

- · PCL and PCLATH
- Stack
- · Indirect Addressing

3.1 Program Memory Organization

The enhanced mid-range core has a 15-bit program counter capable of addressing a 32K x 14 program memory space. Table 3-1 shows the memory sizes implemented for the PIC16(L)F1826/27 family. Accessing a location above these boundaries will cause a wrap-around within the implemented memory space. The Reset vector is at 0000h and the interrupt vector is at 0004h (see Figures 3-1 and 3-2).

TABLE 3-1: DEVICE SIZES AND ADDRESSES

Device	Program Memory Space (Words)	Last Program Memory Address
PIC16(L)F1826	2,048	07FFh
PIC16(L)F1827	4,096	0FFFh

FIGURE 3-1: PROGRAM MEMORY MAP AND STACK FOR PIC16(L)F1826

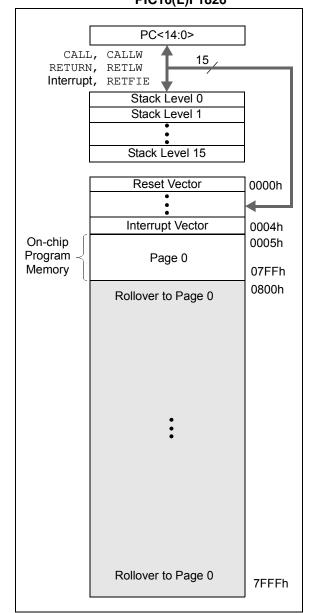
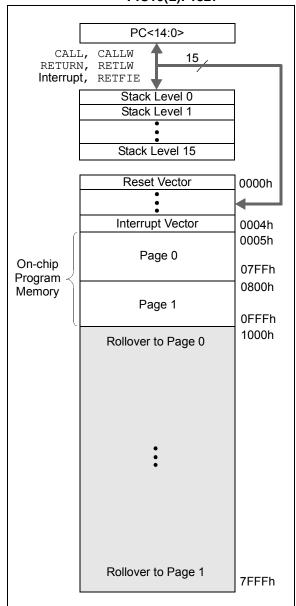


FIGURE 3-2: PROGRAM MEMORY MAP AND STACK FOR PIC16(L)F1827



3.1.1 READING PROGRAM MEMORY AS DATA

There are two methods of accessing constants in program memory. The first method is to use tables of RETLW instructions. The second method is to set an FSR to point to the program memory.

3.1.1.1 RETLW Instruction

The RETLW instruction can be used to provide access to tables of constants. The recommended way to create such a table is shown in Example 3-1.

EXAMPLE 3-1: RETLW INSTRUCTION

```
constants
                     ;Add Index in W to
   BRW
                     ;program counter to
                     ;select data
   RETLW DATA0
                    ;Index0 data
                    ;Index1 data
   RETLW DATA1
   RETLW DATA2
   RETLW DATA3
my_function
   ; ... LOTS OF CODE...
   MOVLW DATA_INDEX
   call constants
   ;... THE CONSTANT IS IN W
```

The BRW instruction makes this type of table very simple to implement. If your code must remain portable with previous generations of microcontrollers, then the BRW instruction is not available so the older table read method must be used.

3.1.1.2 Indirect Read with FSR

The program memory can be accessed as data by setting bit 7 of the FSRxH register and reading the matching INDFx register. The MOVIW instruction will place the lower 8 bits of the addressed word in the W register. Writes to the program memory cannot be performed via the INDF registers. Instructions that access the program memory via the FSR require one extra instruction cycle to complete. Example 3-2 demonstrates accessing the program memory via an FSR.

The HIGH directive will set bit<7> if a label points to a location in program memory.

EXAMPLE 3-2: ACCESSING PROGRAM MEMORY VIA FSR

```
constants
   RETLW DATA0
                      ;Index0 data
   RETLW DATA1
                      ;Index1 data
   RETLW DATA2
   RETLW DATA3
my_function
   ; ... LOTS OF CODE ...
   MOVLW LOW constants
   MOVWF FSR1L
   MOVLW
          HIGH constants
   MOVWF
          FSR1H
   MOVIW 0[FSR1]
; THE PROGRAM MEMORY IS IN W
```

3.2 Data Memory Organization

The data memory is partitioned in 32 memory banks with 128 bytes in a bank. Each bank consists of (Figure 3-3):

- · 12 core registers
- · 20 Special Function Registers (SFR)
- Up to 80 bytes of General Purpose RAM (GPR)
- · 16 bytes of common RAM

The active bank is selected by writing the bank number into the Bank Select Register (BSR). Unimplemented memory will read as '0'. All data memory can be accessed either directly (via instructions that use the file registers) or indirectly via the two File Select Registers (FSR). See Section 3.5 "Indirect Addressing" for more information.

Data Memory uses a 12-bit address. The upper 7-bit of the address define the Bank address and the lower 5-bits select the registers/RAM in that bank.

3.2.1 CORE REGISTERS

The core registers contain the registers that directly affect the basic operation. The core registers occupy the first 12 addresses of every data memory bank (addresses x00h/x08h through x0Bh/x8Bh). These registers are listed below in Table 3-2. For for detailed information, see Table 3-5.

TABLE 3-2: CORE REGISTERS

Addresses	BANKx
x00h or x80h	INDF0
x01h or x81h	INDF1
x02h or x82h	PCL
x03h or x83h	STATUS
x04h or x84h	FSR0L
x05h or x85h	FSR0H
x06h or x86h	FSR1L
x07h or x87h	FSR1H
x08h or x88h	BSR
x09h or x89h	WREG
x0Ah or x8Ah	PCLATH
x0Bh or x8Bh	INTCON

3.2.1.1 STATUS Register

The STATUS register, shown in Register 3-1, contains:

- · the arithmetic status of the ALU
- · the Reset status

The STATUS register can be the destination for any instruction, like any other register. If the STATUS register is the destination for an instruction that affects the Z, DC or C bits, then the write to these three bits is disabled. These bits are set or cleared according to the device logic. Furthermore, the $\overline{\text{TO}}$ and $\overline{\text{PD}}$ bits are not writable. Therefore, the result of an instruction with the STATUS register as destination may be different than intended.

For example, CLRF STATUS will clear the upper three bits and set the Z bit. This leaves the STATUS register as '000u u1uu' (where u = unchanged).

It is recommended, therefore, that only BCF, BSF, SWAPF and MOVWF instructions are used to alter the STATUS register, because these instructions do not affect any Status bits. For other instructions not affecting any Status bits (Refer to Section 29.0 "Instruction Set Summary").

Note 1: The <u>C and DC</u> bits operate as Borrow and Digit Borrow out bits, respectively, in subtraction.

REGISTER 3-1: STATUS: STATUS REGISTER

U-0	U-0	U-0	R-1/q	R-1/q	R/W-0/u	R/W-0/u	R/W-0/u
_	_	_	TO	PD	Z	DC ⁽¹⁾	C ⁽¹⁾
bit 7							bit 0

Legend:		
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '0'
u = Bit is unchanged	x = Bit is unknown	-n/n = Value at POR and BOR/Value at all other Resets
'1' = Bit is set	'0' = Bit is cleared	q = Value depends on condition

bit 7-5	Unimplemented: Read as '0'
טונ ו -ט	Ollillible Hellieu. Neau as 0

bit 4 **TO:** Time-out bit

1 = After power-up, CLRWDT instruction or SLEEP instruction

0 = A WDT time-out occurred

bit 3 **PD:** Power-down bit

1 = After power-up or by the ${\tt CLRWDT}$ instruction

0 = By execution of the SLEEP instruction

bit 2 Z: Zero bit

1 = The result of an arithmetic or logic operation is zero

0 = The result of an arithmetic or logic operation is not zero

bit 1 DC: Digit Carry/Digit Borrow bit (ADDWF, ADDLW, SUBLW, SUBWF instructions)(1)

1 = A carry-out from the 4th low-order bit of the result occurred

0 = No carry-out from the 4th low-order bit of the result

bit 0 C: Carry/Borrow bit⁽¹⁾ (ADDWF, ADDLW, SUBLW, SUBWF instructions)⁽¹⁾

1 = A carry-out from the Most Significant bit of the result occurred

0 = No carry-out from the Most Significant bit of the result occurred

Note 1: For Borrow, the polarity is reversed. A subtraction is executed by adding the two's complement of the second operand. For rotate (RRF, RLF) instructions, this bit is loaded with either the high-order or low-order bit of the source register.

3.2.2 SPECIAL FUNCTION REGISTER

The Special Function Registers are registers used by the application to control the desired operation of peripheral functions in the device. The Special Function Registers occupy the 20 bytes after the core registers of every data memory bank (addresses x0Ch/x8Ch through x1Fh/x9Fh). The registers associated with the operation of the peripherals are described in the appropriate peripheral chapter of this data sheet.

3.2.3 GENERAL PURPOSE RAM

There are up to 80 bytes of GPR in each data memory bank. The Special Function Registers occupy the 20 bytes after the core registers of every data memory bank (addresses x0Ch/x8Ch through x1Fh/x9Fh).

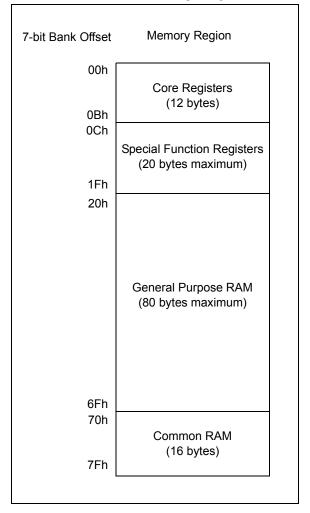
3.2.3.1 Linear Access to GPR

The general purpose RAM can be accessed in a non-banked method via the FSRs. This can simplify access to large memory structures. See **Section 3.5.2** "Linear Data Memory" for more information.

3.2.4 COMMON RAM

There are 16 bytes of common RAM accessible from all banks.

FIGURE 3-3: BANKED MEMORY PARTITIONING



3.2.5 DEVICE MEMORY MAPS

The memory maps for the device family are as shown in Table 3-3 and Table 3-4.

TABLE 3-3: PIC16(L)F1826/27 MEMORY MAP															
	BANK 0	•	BANK 1		BANK 2		BANK 3		BANK 4		BANK 5		BANK 6		BANK 7
000h		080h		100h		180h		200h		280h		300h		380h	
	Core Registers (Table 3-2)		Core Registers (Table 3-2)		Core Registers (Table 3-2)		Core Registers (Table 3-2)		Core Registers (Table 3-2)		Core Registers (Table 3-2)		Core Registers (Table 3-2)		Core Registers (Table 3-2)
00Bh		08Bh		10Bh		18Bh		20Bh		28Bh		30Bh		38Bh	
00Ch	PORTA	08Ch	TRISA	10Ch	LATA	18Ch	ANSELA	20Ch	WPUA	28Ch	_	30Ch	_	38Ch	_
00Dh	PORTB	08Dh	TRISB	10Dh	LATB	18Dh	ANSELB	20Dh	WPUB	28Dh	_	30Dh	_	38Dh	_
00Eh		08Eh	_	10Eh		18Eh		20Eh		28Eh		30Eh	_	38Eh	_
00Fh		08Fh	_	10Fh		18Fh		20Fh		28Fh		30Fh		38Fh	_
010h		090h		110h		190h		210h	_	290h		310h		390h	_
011h	PIR1	091h	PIE1	111h	CM1CON0	191h	EEADRL	211h	SSP1BUF	291h	CCPR1L	311h	CCPR3L ⁽¹⁾	391h	_
012h	PIR2	092h	PIE2	112h	CM1CON1	192h	EEADRH	212h	SSP1ADD	292h	CCPR1H	312h	CCPR3H ⁽¹⁾	392h	_
013h	PIR3 ⁽¹⁾	093h	PIE3 ⁽¹⁾	113h	CM2CON0	193h	EEDATL	213h	SSP1MASK	293h	CCP1CON	313h	CCP3CON ⁽¹⁾	393h	_
014h	PIR4 ⁽¹⁾	094h	PIE4 ⁽¹⁾	114h	CM2CON1	194h	EEDATH	214h	SSP1STAT	294h	PWM1CON	314h	_	394h	IOCBP
015h	TMR0	095h	OPTION	115h	CMOUT	195h	EECON1	215h	SSP1CON	295h	CCP1AS	315h	_	395h	IOCBN
016h	TMR1L	096h	PCON	116h	BORCON	196h	EECON2	216h	SSP1CON2	296h	PSTR1CON	316h	_	396h	IOCBF
017h	TMR1H	097h	WDTCON	117h	FVRCON	197h		217h	SSP1CON3	297h		317h		397h	_
018h	T1CON	098h	OSCTUNE	118h	DACCON0	198h	_	218h	_	298h	CCPR2L ⁽¹⁾	318h	CCPR4L ⁽¹⁾	398h	_
019h	T1GCON	099h	OSCCON	119h	DACCON1	199h	RCREG	219h	SSP2BUF ⁽¹⁾	299h	CCPR2H ⁽¹⁾	319h	CCPR4H ⁽¹⁾	399h	_
01Ah	TMR2	09Ah	OSCSTAT	11Ah	SRCON0	19Ah	TXREG	21Ah	SSP2ADD ⁽¹⁾	29Ah	CCP2CON ⁽¹⁾	31Ah	CCP4CON ⁽¹⁾	39Ah	CLKRCON
01Bh	PR2	09Bh	ADRESL	11Bh	SRCON1	19Bh	SPBRGL	21Bh	SSP2MASK ⁽¹⁾	29Bh	PWM2CON ⁽¹⁾	31Bh	_	39Bh	_
01Ch	T2CON	09Ch	ADRESH	11Ch	_	19Ch	SPBRGH	21Ch	SSP2STAT ⁽¹⁾	29Ch	CCP2AS ⁽¹⁾	31Ch	_	39Ch	MDCON
01Dh	_	09Dh	ADCON0	11Dh	APFCON0	19Dh	RCSTA	21Dh	SSP2CON ⁽¹⁾	29Dh	PSTR2CON ⁽¹⁾	31Dh	_	39Dh	MDSRC
01Eh	CPSCON0	09Eh	ADCON1	11Eh	APFCON1	19Eh	TXSTA	21Eh	SSP2CON2 ⁽¹⁾	29Eh	CCPTMRS ⁽¹⁾	31Eh	_	39Eh	MDCARL
01Fh	CPSCON1	09Fh	1	11Fh	_	19Fh	BAUDCON	21Fh	SSP2CON3 ⁽¹⁾	29Fh	_	31Fh	_	39Fh	MDCARH
020h	General	0A0h	General Purpose Register	120h	General Purpose Register	1A0h	General Purpose Register	220h	General Purpose Register 48 Bytes ⁽¹⁾	2A0h	Unimplemented Read as '0'	320h	Unimplemented Read as '0'	3A0h	Unimplemented Read as '0'
06Fh	Purpose Register 96 Bytes	0EFh	80 Bytes	16Fh	80 Bytes	1EFh	80 Bytes ⁽¹⁾	26Fh	Unimplemented Read as '0'	2EFh	Noud do	36Fh	riodd do 0	3EFh	ricad do v
070h	00 Byte5	0F0h	Accesses 70h – 7Fh	170h	Accesses 70h – 7Fh	1F0h	Accesses 70h – 7Fh	270h	Accesses 70h – 7Fh	2F0h	Accesses 70h – 7Fh	370h	Accesses 70h – 7Fh	3F0h	Accesses 70h – 7Fh
07Fh		0FFh		17Fh		1FFh		27Fh		2FFh		37Fh		3FFh	

Legend: = Unimplemented data memory locations, read as '0'

Note 1: Available only on PIC16(L)F1827.

	BANK 8		BANK 9		BANK 10		BANK 11		BANK 12		BANK 13		BANK 14		BANK 15
400h	Core Registers (Table 3-2)	480h	Core Registers (Table 3-2)	500h	Core Registers (Table 3-2)	580h	Core Registers (Table 3-2)	600h	Core Registers (Table 3-2)	680h	Core Registers (Table 3-2)	700h	Core Registers (Table 3-2)	780h	Core Registers (Table 3-2)
40Bh		48Bh		50Bh		58Bh		60Bh		68Bh		70Bh		78Bh	
40Ch	_	48Ch		50Ch		58Ch		60Ch		68Ch		70Ch		78Ch	1
40Dh	_	48Dh	_	50Dh	_	58Dh	_	60Dh	_	68Dh	_	70Dh	_	78Dh	_
40Eh	_	48Eh	_	50Eh		58Eh		60Eh		68Eh	_	70Eh		78Eh	-
40Fh	_	48Fh		50Fh		58Fh		60Fh		68Fh	_	70Fh		78Fh	1
410h	_	490h	_	510h		590h	_	610h	_	690h		710h	_	790h	_
411h	_	491h	_	511h		591h	_	611h	_	691h	_	711h	_	791h	
412h	_	492h	_	512h		592h	_	612h	_	692h	_	712h	_	792h	_
413h	_	493h	_	513h		593h	_	613h	_	693h	_	713h	_	793h	_
414h		494h	_	514h		594h	_	614h	_	694h	_	714h	_	794h	
415h	TMR4 ⁽¹⁾	495h	_	515h	_	595h	_	615h	_	695h	_	715h	_	795h	_
416h	PR4 ⁽¹⁾	496h		516h	_	596h		616h		696h	_	716h		796h	
417h	T4CON ⁽¹⁾	497h	_	517h	_	597h	_	617h	_	697h	_	717h	_	797h	_
418h	_	498h		518h	_	598h		618h		698h		718h		798h	
419h	_	499h	1	519h	_	599h	1	619h	1	699h		719h	1	799h	
41Ah	_	49Ah		51Ah	_	59Ah		61Ah		69Ah	ı	71Ah		79Ah	ı
41Bh	_	49Bh	_	51Bh		59Bh	_	61Bh	_	69Bh	_	71Bh	_	79Bh	_
41Ch	TMR6 ⁽¹⁾	49Ch		51Ch	_	59Ch	-	61Ch	-	69Ch	_	71Ch	-	79Ch	_
41Dh	PR6 ⁽¹⁾	49Dh	_	51Dh	_	59Dh	_	61Dh	_	69Dh	_	71Dh	_	79Dh	_
41Eh	T6CON ⁽¹⁾	49Eh	-	51Eh	_	59Eh	-	61Eh	-	69Eh	_	71Eh	-	79Eh	_
41Fh	_	49Fh	_	51Fh	_	59Fh	_	61Fh	_	69Fh	_	71Fh	_	79Fh	-
420h		4A0h		520h		5A0h		620h		6A0h		720h		7A0h	
	Unimplemented Read as '0'														
46Fh		4EFh		56Fh		5EFh		66Fh		6EFh		76Fh		7EFh	
470h		4F0h		570h		5F0h		670h		6F0h		770h		7F0h	
	Accesses 70h – 7Fh														

Legend: = Unimplemented data memory locations, read as '0'

TABLE 3-3: PIC16(L)F1826/27 MEMORY MAP (CONTINUED)

	BANK16		BANK17		BANK18		BANK19		BANK20		BANK21		BANK22		BANK23
800h	Core Registers (Table 3-2)	880h	Core Registers (Table 3-2)	900h	Core Registers (Table 3-2)	980h	Core Registers (Table 3-2)	A00h	Core Registers (Table 3-2)	A80h	Core Registers (Table 3-2)	B00h	Core Registers (Table 3-2)	B80h	Core Registers (Table 3-2)
80Bh		88Bh		90Bh		98Bh		A0Bh		A8Bh		B0Bh		B8Bh	
80Ch		88Ch		90Ch		98Ch		A0Ch		A8Ch		B0Ch		B8Ch	
	Unimplemented Read as '0'														
86Fh		8EFh		96Fh		9EFh		A6Fh		AEFh		B6Fh		BEFh	
870h	Common RAM (Accesses 70h – 7Fh)	8F0h	Common RAM (Accesses 70h – 7Fh)	970h	Common RAM (Accesses 70h – 7Fh)	9F0h	Common RAM (Accesses 70h – 7Fh)	A70h	Common RAM (Accesses 70h – 7Fh)	AF0h	Common RAM (Accesses 70h – 7Fh)	B70h	Common RAM (Accesses 70h – 7Fh)	BF0h	Common RAM (Accesses 70h – 7Fh)
87Fh		8FFh		97Fh		9FFh		A7Fh		AFFh		B7Fh		BFFh	

	BANK 24		BANK 25		BANK 26		BANK 27		BANK 28		BANK 29		BANK 30		BANK 31
C00h	Core Registers (Table 3-2)	C80h	Core Registers (Table 3-2)	D00h	Core Registers (Table 3-2)	D80h	Core Registers (Table 3-2)	E00h	Core Registers (Table 3-2)	E80h	Core Registers (Table 3-2)	F00h	Core Registers (Table 3-2)	F80h	Core Registers (Table 3-2)
C0Bh		C8Bh		D0Bh		D8Bh		E0Bh		E8Bh		F0Bh		F8Bh	
C0Ch		C8Ch		D0Ch		D8Ch		E0Ch		E8Ch		F0Ch		F8Ch	
C6Fh	Unimplemented Read as '0'	CEFh	Unimplemented Read as '0'	D6Fh	Unimplemented Read as '0'	DEFh	Unimplemented Read as '0'	E6Fh	Unimplemented Read as '0'	EEFh	Unimplemented Read as '0'	F6Fh	Unimplemented Read as '0'	F9Fh FA0h FEFh	Unimplemented Read as '0' See Table 3-4 for more information
C70h C7Fh	Accesses 70h – 7Fh	CF0h	Accesses 70h – 7Fh	D70h D7Fh	Accesses 70h – 7Fh	DF0h	Accesses 70h – 7Fh	E70h E7Fh	Accesses 70h – 7Fh	EF0h	Accesses 70h – 7Fh	F70h F7Fh	Common RAM (Accesses 70h – 7Fh)	FF0h	Common RAM (Accesses 70h – 7Fh)

Legend: = Unimplemented data memory locations, read as '0'